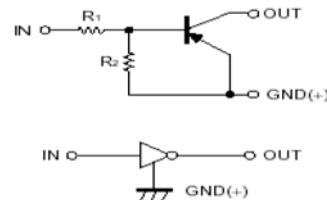


## Digital Transistor

## DTA(R<sub>1</sub>=R<sub>2</sub> SERIES)E

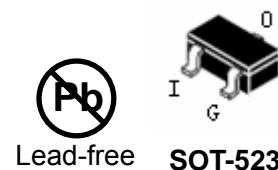
### FEATURES

- Epitaxial planar die construction.
- Complementary NPN types available(DTC).
- Built-in biasing resistors,R<sub>1</sub>=R<sub>2</sub>.
- Also available in lead free version.



### APPLICATIONS

- The PNP style digital transistor.



### ORDERING INFORMATION

Type No.	Marking	Package Code
DTA114EE	14	SOT-523
DTA124EE	15	SOT-523
DTA143EE	13	SOT-523
DTA144EE	16	SOT-523

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Units
V <sub>CC</sub>	Supply Voltage	-50	V
V <sub>IN</sub>	Input Voltage DTA114EE	+10 to -40	V
	DTA124EE	+10 to -40	
	DTA143EE	+10 to -30	
	DTA144EE	+10 to -40	
I <sub>O</sub>	Output Current DTA114EE	-50	mA
	DTA124EE	-30	
	DTA143EE	-100	
	DTA144EE	-30	
I <sub>C</sub> (Max.)	Output current ALL	-100	mA
P <sub>D</sub>	Power Dissipation	150	mW
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient Air	833	°C/W
T <sub>j</sub> , T <sub>stg</sub>	Operating and Storage and Temperature Range	-55 to +150	°C

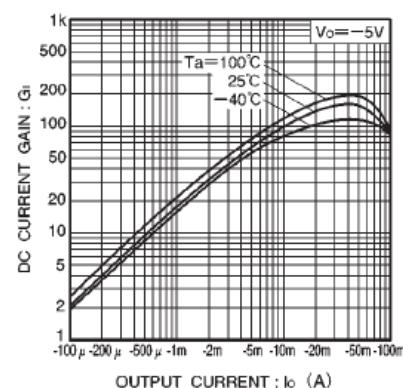
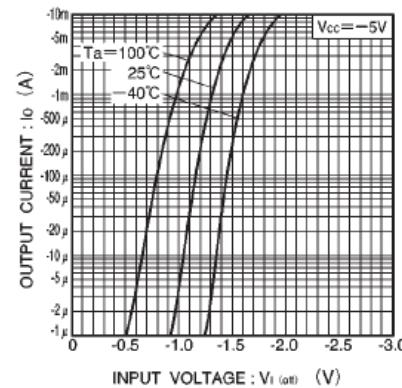
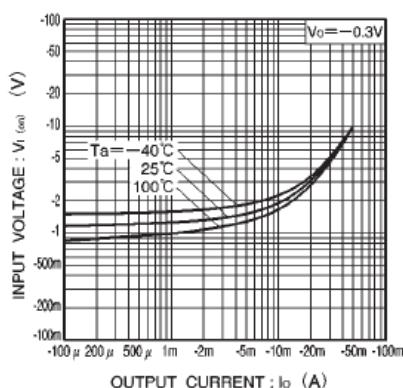
## Digital Transistor

## DTA(R<sub>1</sub>=R<sub>2</sub> SERIES)E

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Input Voltage	V <sub>I(off)</sub>	V <sub>CC</sub> =-5V, I <sub>O</sub> =-100μA	-0.5	-1.1	-	
Input Voltage	V <sub>I(on)</sub>	V <sub>O</sub> =-0.3V, I <sub>O</sub> =-10mA	-	-1.9	-3	V
		V <sub>O</sub> =-0.2V, I <sub>O</sub> =-5mA				
		V <sub>O</sub> =-0.3V, I <sub>O</sub> =-20mA				
		V <sub>O</sub> =-0.3V, I <sub>O</sub> =-2mA				
Output Voltage	V <sub>O(on)</sub>	I <sub>O</sub> /I <sub>I</sub> =-10mA/-0.5mA,	-	-0.1	-0.3	V
Input Current	I <sub>I</sub>	V <sub>I</sub> =-5V	-	-	-0.88 -0.36 -1.8 -0.18	mA
Output Current	I <sub>O(off)</sub>	V <sub>CC</sub> =-50V, V <sub>I</sub> =0V	-	-	-0.5	μA
DC Current Gain	G <sub>I</sub>	V <sub>O</sub> =-5V, I <sub>O</sub> =-5mA	30	-	-	
		V <sub>O</sub> =-5V, I <sub>O</sub> =-5mA	56			
		V <sub>O</sub> =-5V, I <sub>O</sub> =-10mA	20			
		V <sub>O</sub> =-5V, I <sub>O</sub> =-5mA	68			
Input Resistor	R <sub>1</sub> (R <sub>2</sub> )		7	10	13	
			15.4	22	28.6	
			3.29	4.7	6.11	
			32.9	47	61.1	kΩ
Resistance Ratio	R <sub>2</sub> /R <sub>1</sub>	-	0.8	1	1.2	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =-10V, I <sub>E</sub> =5mA, f=100MHz	-	250	-	MHz

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified



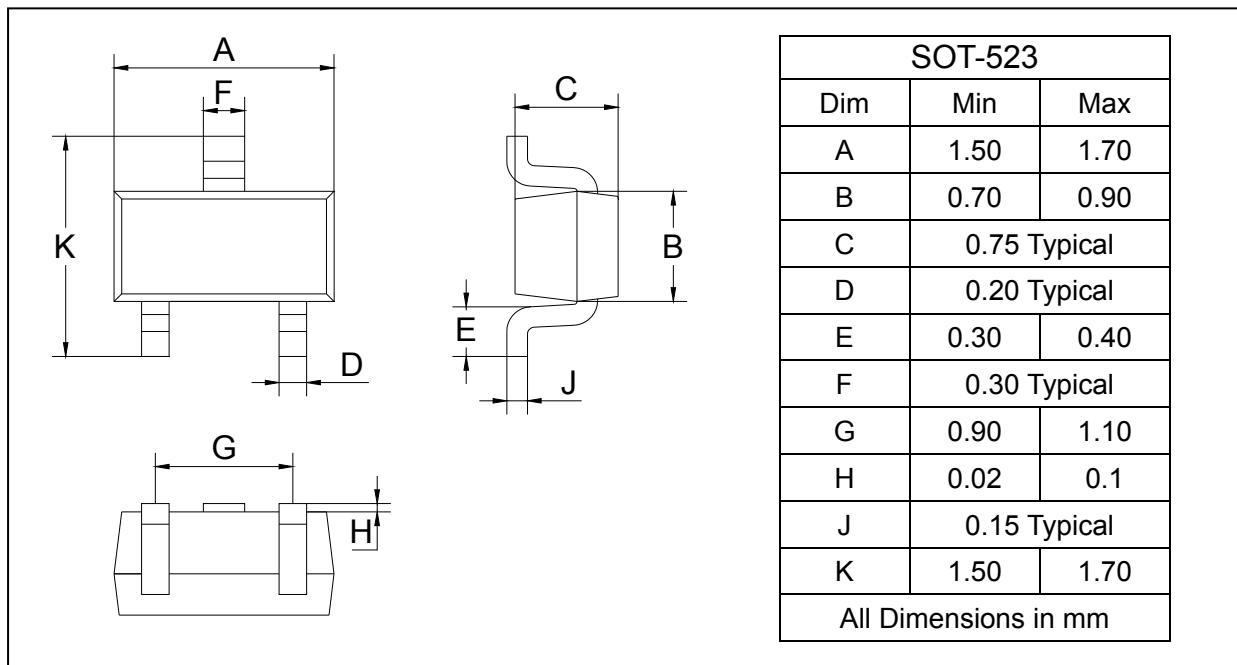
## Digital Transistor

## DTA(R<sub>1</sub>=R<sub>2</sub> SERIES)E

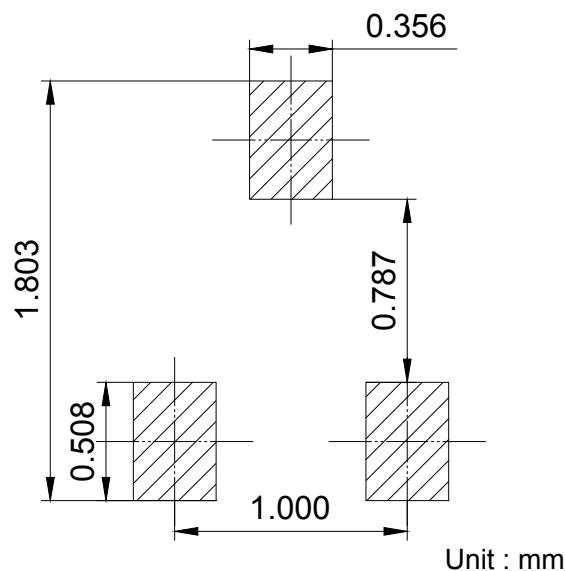
### PACKAGE OUTLINE

Plastic surface mounted package

SOT-523



### SOLDERING FOOTPRINT



### PACKAGE INFORMATION

Device	Package	Shipping
DTA114EE/124EE/143EE/144EE	SOT-523	3000/Tape&Reel